Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V_{BE} = 0V)	V_{CES}	700	V
Collector-Emitter Voltage	V_{CEO}	450	V
Emitter-Base Voltage	V_{EBO}	9	V
Continuous Collector Current	I_C	1.3	A
Peak Pulse Collector Current (Note 5)	I_{CM}	2.6	A
Continuous Base Current	I_B	0.65	A
Peak Pulse Base Current (Note 5)	I_{BM}	1.3	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

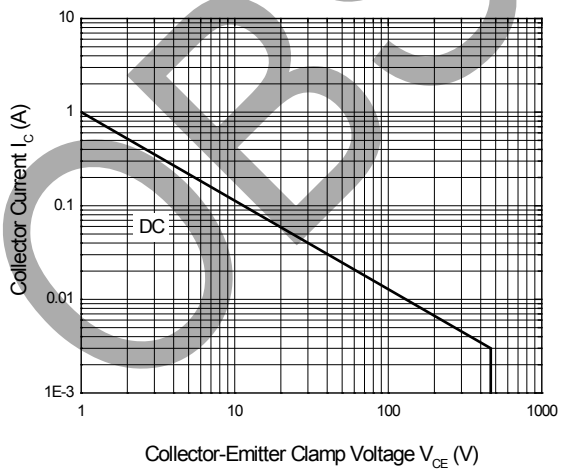
Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	1.1	W
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	113.6	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Note: 5. Pulse test for Pulse Width < 5ms, Duty Cycle ≤ 10%.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Area and Derating Information (@T_A = +25°C, unless otherwise specified.)



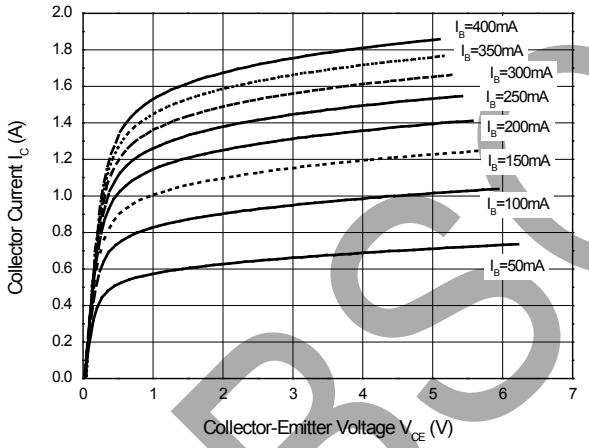
Safe Operating Areas (TO92 Package)

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

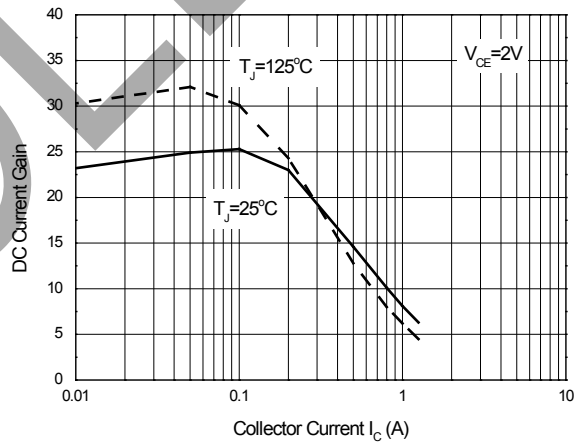
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV_{CES}	700	—	—	V	I_C = 100μA, V_{BE} = 0V
Collector-Emitter Breakdown Voltage	BV_{CEO}	450	—	—	V	I_C = 100μA
Emitter-Base Breakdown Voltage	BV_{EBO}	9	—	—	V	I_E = 100μA
Collector Cutoff Current	I_{CEV}	—	—	10	μA	V_{CE} = 700V, V_{BE} = -1.5V
DC Current Transfer Static Ratio (Note 7)	h_{FE}	13 5	— —	30 25	—	I_C = 0.5A, V_{CE} = 2V I_C = 1.0A, V_{CE} = 2V
Collector-Emitter Saturation Voltage (Note 7)	$V_{CE(sat)}$	— —	— —	0.3 0.6	V	I_C = 0.5A, I_B = 0.1A I_C = 1A, I_B = 0.25A
Base-Emitter Saturation Voltage (Note 7)	$V_{BE(sat)}$	— —	— —	1.0 1.2	V	I_C = 0.5A, I_B = 0.1A I_C = 1A, I_B = 0.25A
Transition Frequency	f_T	4	—	—	MHz	I_C = 0.1A, V_{CE} = 10V
Turn-on Time with Resistive Load	t_{on}	—	—	1	μs	I_C = 1A, V_{CC} = 125V, I_{B1} = 0.2A, I_{B2} = -0.2A, t_p = 25μs
Storage Time with Resistive Load	t_s	—	—	3		
Fall Time with Resistive Load	t_f	—	—	0.5		

Note: 7. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

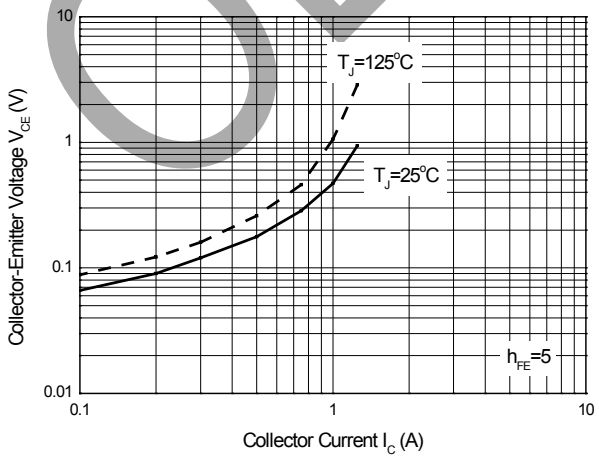
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



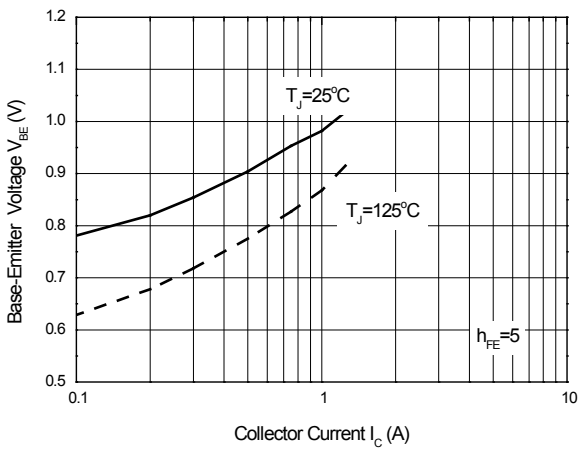
Static Characteristics



DC Current Gain



Collector-Emitter Saturation Voltage

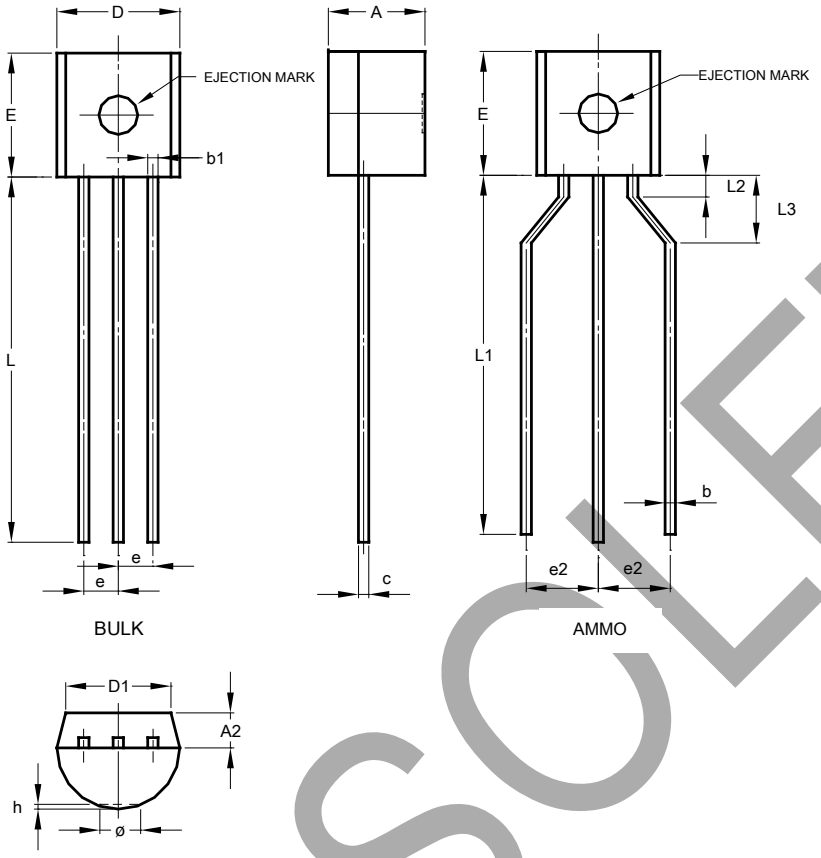


Base-Emitter Saturation Voltage

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO92 (Type C)



TO92 (Type C)			
Dim	**Min**	**Max**	**Typ**
A	3.30	3.70	-
A2	1.10	1.40	-
b	0.38	0.55	-
c	0.36	0.51	-
D	4.40	4.70	-
D1	3.430	-	-
E	4.30	4.70	-
e	-	-	1.27
e2	2.440	2.640	-
h	0.00	0.38	-
L	14.10	14.50	-
L1	12.50	14.50	-
L3	2.50	3.50	-
ø	-	1.60	-
All Dimensions in mm			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.

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